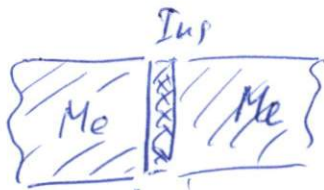
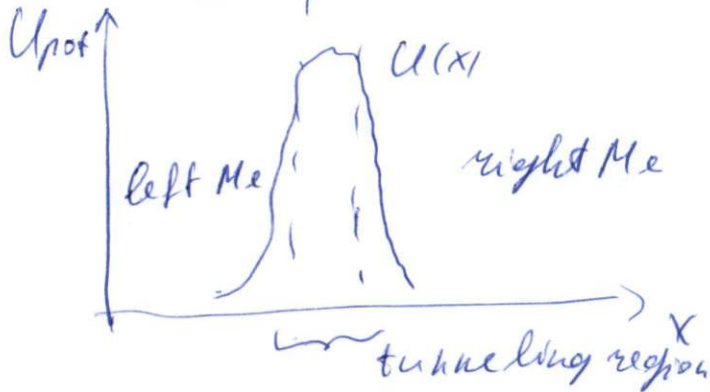


Tunneling in NIS & SIS junctions

(a)



- to Me-samples separated by a potential barrier



- can be described by the tunneling \hat{H} :

$$\hat{H} = \hat{H}_{L-Me} + \hat{H}_{R-Me} + \hat{H}_{tun}$$

where $\hat{H}_{tun} = \sum_{\text{all}} \{ T_{pq} \hat{a}_{p,0}^\dagger \hat{b}_{q,0} + \text{h.c.} \}$

\hat{a}^\dagger, \hat{a} - for left-Me ; \hat{b}^\dagger, \hat{b} - for right-Me

Total current

$$J_{\text{tot}} = J_R - J_L$$

where currents in right/left-Me can be found as

$$J_{L,R} = e \left\langle \frac{d}{dt} \hat{N}_{L,R} \right\rangle_{\text{particle number operator}}$$

$$\frac{d}{dt} \hat{N}_{L,R} = i\hbar [\hat{H}, \hat{N}_{L,R}] = i\hbar [\hat{H}_{tun}, \hat{N}_{L,R}]$$

This yields (see Yan's lecture "Single e tunneling" or Abrikosov's book, sect. 22.3) at finite applied V average (around eV) DOS of L/R-Me

$$J_{\text{tot}} = + \frac{4\pi e}{\hbar} |\bar{T}|^2 \int d\varepsilon \underbrace{v_L(\varepsilon - eV) v_R(\varepsilon)}_{\text{DOS of L/R-Me}}$$

$$\left[f(\varepsilon - eV) [1 - f(\varepsilon)] - f(\varepsilon) [1 - f(\varepsilon - eV)] \right]$$

the Fermi-factors

$$= + \frac{4\pi e}{\hbar} |\bar{T}|^2 \int d\varepsilon V_L(\varepsilon - eV) V_R(\varepsilon) (f(\varepsilon - eV) - f(\varepsilon)) \quad (6)$$

Case NIN \Rightarrow at $V_L \approx V_R = V(\varepsilon_F) = \text{const}$

$$I_{\text{tot}} = + \frac{4\pi e}{\hbar} |\bar{T}|^2 V(\varepsilon_F) \int d\varepsilon (f(\varepsilon - eV) - f(\varepsilon))$$


$\approx eV$

$$\Rightarrow \frac{I_{\text{tot}}}{S} = G V, \quad G = \frac{4\pi e^2}{\hbar} \frac{|\bar{T}|^2 V^2(\varepsilon_F)}{S}$$

Ohm's law L square of the contact.

Case NIS take $T \rightarrow 0$

$$I_{\text{tot}} = \frac{4\pi e}{\hbar} |\bar{T}|^2 V_L(\varepsilon_F) \int d\varepsilon V_R^{(sc)}(\varepsilon) [f(\varepsilon - eV) - f(\varepsilon)]$$

step function 

$$\Rightarrow I_{\text{tot}} = \frac{4\pi e}{\hbar} |\bar{T}|^2 V_L(\varepsilon_F) \int_0^{eV} d\varepsilon V_R^{(sc)}(\varepsilon)$$

where $V_R^{(sc)}(\varepsilon) = V_R \text{Re} \left(\frac{\varepsilon}{\sqrt{\varepsilon^2 - \Delta^2}} \right) = V_R \text{Re} \partial_\varepsilon \sqrt{\varepsilon^2 - \Delta^2}$

$$\Rightarrow I_{\text{tot}} = 0 \text{ at } eV < \Delta$$

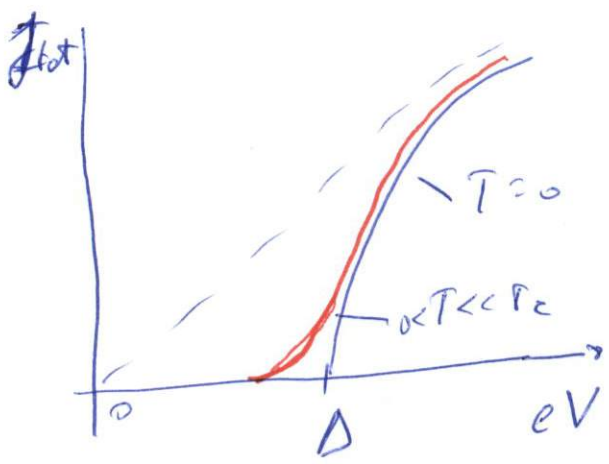
$$I_{\text{tot}} = \frac{4\pi e}{\hbar} |\bar{T}|^2 V_L(\varepsilon_F) V_R(\varepsilon_F) \int_\Delta^{eV} d\varepsilon \frac{d}{d\varepsilon} \sqrt{\varepsilon^2 - \Delta^2} =$$

$$= \frac{4\pi e}{\hbar} |\bar{T}|^2 V_L(\varepsilon_F) V_R(\varepsilon_F) \sqrt{(eV)^2 - \Delta^2} \text{ at } eV > \Delta$$

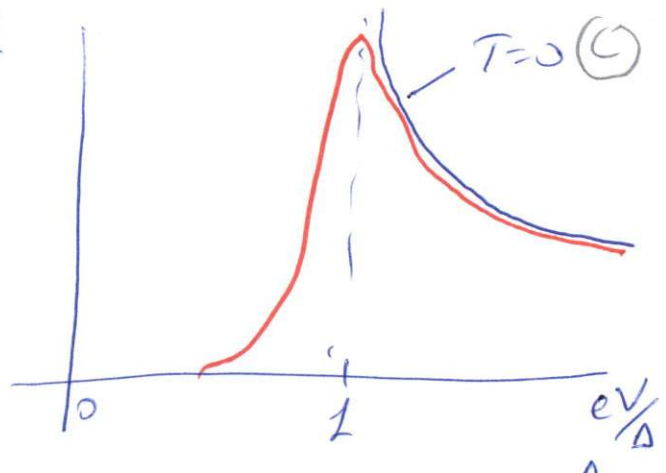
~~the same as above~~

Finite Temp. yields broadening:

Important: $\frac{dI_{\text{tot}}}{dV} = \text{const } V_R^{(sc)}(eV)$

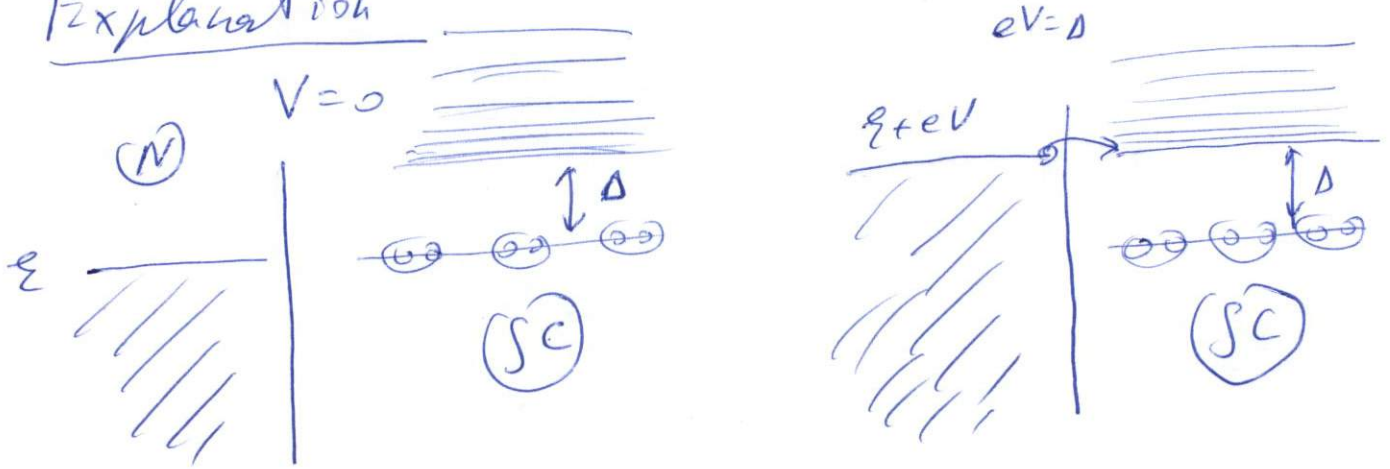


$$\frac{dJ_{tot}}{dE}$$

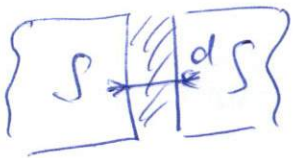


at $T \ll T_c$ tails below the gap is small at $e^{-\frac{\Delta}{k_B T}}$

Explanation



Most realistic case SIS or SNS at $V=0$



$d_{typ} \sim 1 \text{ nm}$ for SIS

$d_{typ} \sim 10^3 \text{ nm}$ for SNS

Coherent tunneling of Cooper pairs is possible since d is small - there can be super current at $V=0$, called the Josephson effect (weak sup cond).

Setup: let left-/right sup cond be made from the same material. Introduce the Wf for the bulks at $T_{un}=0$ (disconnected)

$$\Psi_{RIL} = \Psi e^{i\Phi_{RIL}} - \text{describes the coherent condensate of the (-) pairs}$$

Normalization: $|\Psi_{R/L}|^2 = n_{sc}$ - density of particles in the condensate, which is the same if $T_L = T_R$
 \Rightarrow amplitudes are equal $\Psi_R = \Psi_L = \Psi = \sqrt{n_{sc}}$ but phases can be different

$$\begin{cases} \theta = \theta_R, & x > 0 \\ \theta = \theta_L, & x < 0 \end{cases}, \quad \phi = \theta_R - \theta_L \neq 0$$

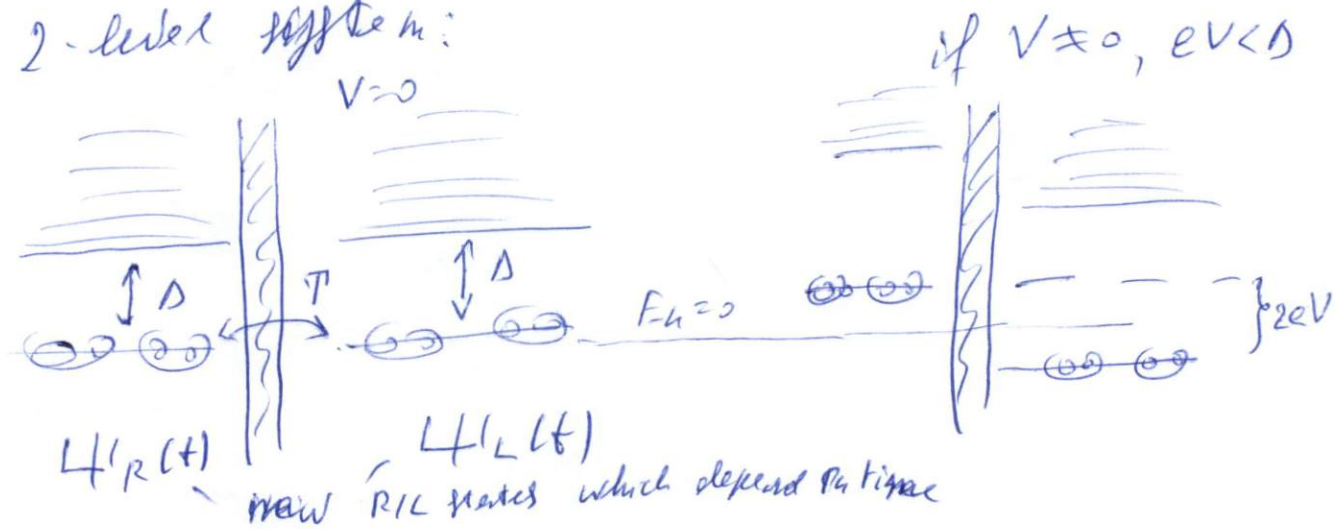
Main idea: $f_{Jor} = f(\phi) \begin{cases} f(0) = 0 \\ f(\phi + 2\pi) = f(\phi) \\ f(-\phi) = -f(\phi) \end{cases}$

The simplest possible case:

$$f_{Jor}/V \rightarrow 0 = J_c \sin \phi$$

where J_c is max of the super-current through the tunneling contact

Calculation can be done starting from the tunneling Hamiltonian or using the Feynman's short-cut: let's model the Josephson junction with the help of 2-level system:



Schrodinger eq. $i\hbar \frac{\partial \Psi}{\partial t} = \hat{H} \Psi$, where $\hat{H} = \begin{pmatrix} H_L & T \\ T & H_R \end{pmatrix}$
 T R \Rightarrow transition probability, $H_{L/R} = \pm eV$ in the basis of initial states

The vector $\psi(t) = \begin{pmatrix} \psi_L(t) \\ \psi_R(t) \end{pmatrix}$ is constructed from (e)

$$\psi_{L/R}(t) = \sqrt{n_{S,R/L}(t)} e^{i\theta_{L/R}(t)}$$

This yields 2 coupled differential equations

$$\begin{cases} i\hbar \frac{d}{dt} \psi_L = eV\psi_L + T\psi_R & \times \psi_L^* \\ i\hbar \frac{d}{dt} \psi_R = T\psi_L - eV\psi_R & \times \psi_R^* \end{cases}$$

$$\Rightarrow \begin{cases} \frac{1}{2} \frac{d}{dt} n_{S,L} + i n_{S,L} \frac{d}{dt} \theta_L = \hbar^{-1} (-i) [eV n_{S,L} + T \sqrt{n_{S,L} n_{S,R}} e^{i\phi}] \\ \frac{1}{2} \frac{d}{dt} n_{S,R} + i n_{S,R} \frac{d}{dt} \theta_R = \hbar^{-1} (-i) [T \sqrt{n_{S,L} n_{S,R}} e^{-i\phi} - eV n_{S,R}] \end{cases}$$

Take the Re:

$$\frac{1}{2} \frac{d}{dt} n_{S,L} = -\frac{1}{2} \frac{d}{dt} n_{S,R} = \frac{T}{\hbar} \frac{\sqrt{n_{S,L} n_{S,R}}}{n_S^2} \sin\phi \approx \frac{T n_S}{\hbar} \sin\phi$$

(in the leading order in T)

$$\boxed{\frac{d}{dt} n_{S,L} = -\frac{d}{dt} n_{S,R} = \frac{2T n_S}{\hbar} \sin\phi}$$

Take the Im:

$$\frac{d}{dt} \theta_L = -\frac{eV}{\hbar} - \frac{T}{\hbar} \sqrt{\frac{n_{S,R}}{n_{S,L}}} \cos\phi \approx -\frac{eV}{\hbar} - \frac{T}{\hbar} \cos\phi$$

$1 + O(T)$

$$\frac{d}{dt} \theta_R = \frac{eV}{\hbar} - \frac{T}{\hbar} \sqrt{\frac{n_{S,L}}{n_{S,R}}} \cos\phi \approx \frac{eV}{\hbar} - \frac{T}{\hbar} \cos\phi$$

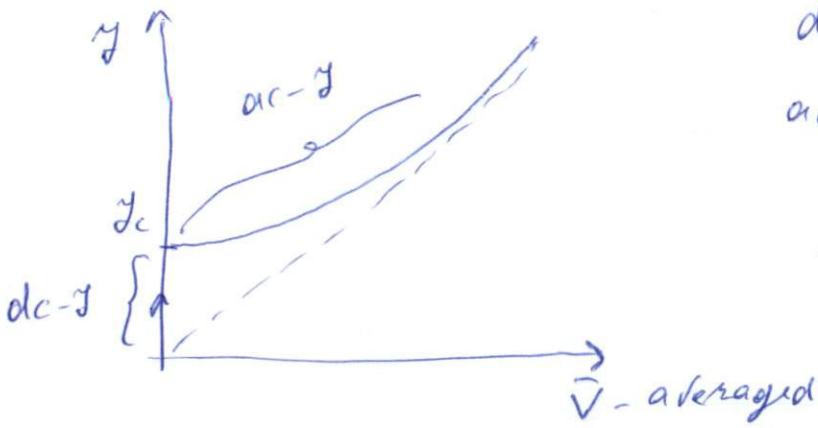
$1 + O(T)$

$$\Rightarrow \boxed{\frac{d}{dt} (\theta_R - \theta_L) = \frac{2eV}{\hbar}}$$

Current $L \rightarrow R$ in the tunneling junction $\propto \frac{dn_{S,L}}{dt} \Rightarrow \boxed{I = I_C \sin\phi}$

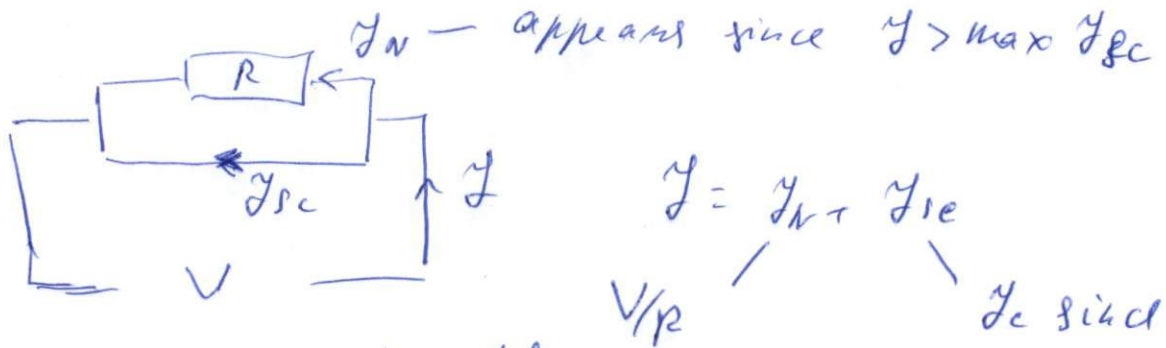
If the current source is applied

(2)



dc: $V=0$ at $|j| < j_c$
 ac: $V(t)$ appears at $|j| > j_c$
 Note $V(t)$ - periodic

$V(t)$ can be explained with the help of the resistive model



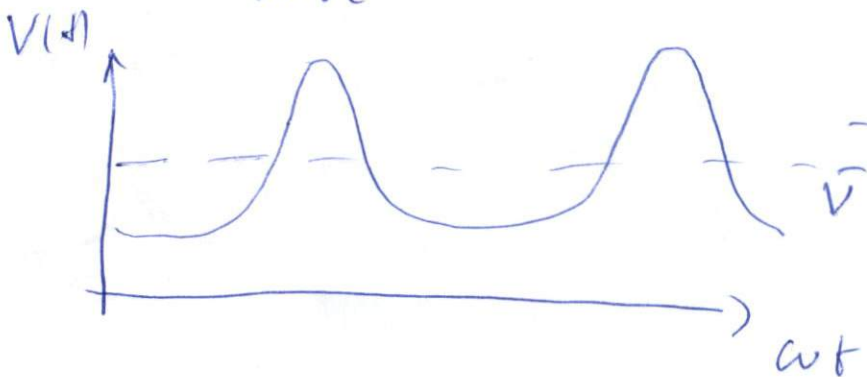
Insert $V = \frac{\hbar}{2e} \frac{dj}{dt}$

$\Rightarrow j = j_c \sin t + \frac{\hbar}{2eR} \frac{\partial j}{\partial t}$

Solving it and finding V yields

$V(t) = R \frac{j^2 - j_c^2}{j + j_c \cos \omega t}$, $\omega = \frac{2e}{\hbar} R \sqrt{j^2 - j_c^2}$

$|j| > j_c$



Joseph's generation of ac $V(t)$

$\bar{V} = \langle V(t) \rangle_t \approx \frac{\hbar \omega}{2e}$

If the voltage source is applied

(9)

$V = \text{const}$ (easy for SIS) \Rightarrow

$$\frac{d}{dt} q = 2 \frac{eV}{\hbar} \Rightarrow q = \frac{2eVt}{\hbar} + q_0$$

and we come across ac current

$$I = I_c \sin\left(q_0 + \frac{2eV}{\hbar} t\right)$$